NSN 5962-01-310-4811

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-310-4811 **Body Length:** 2.435 inches **Body Width:** Between 0.510 inches and 0.620 inches **Body Height:** Between 0.165 inches and 0.210 inches **Maximum Power Dissipation Rating:** 1.5 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and static operation and monolithic and bidirectional **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:**

44 input

Case Outline Source And Designator:

D-14 mil-m-38510

Current Rating Per Characteristic:

50.00 milliamperes forward current, peak total value not applicable

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

90.00 nanoseconds propagation delay time, low to high level output and 90.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Ram

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

48 printed circuit

Shelf Life:

N/a

Unit Of Measure:

__

NSN 5962-01-310-4811

Memory Microcircuit - Page 2 of 2



Demilitarization:

No

Fiig:

A458a0